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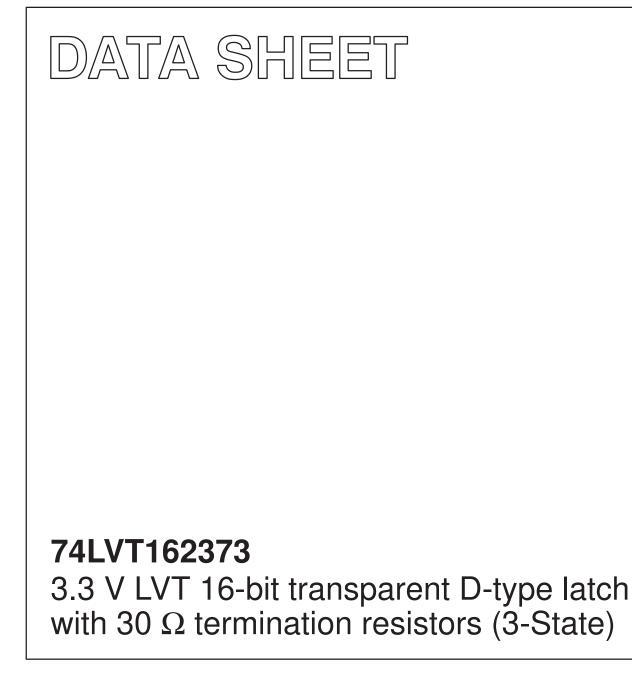
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Kind regards,

Team Nexperia

INTEGRATED CIRCUITS



Product specification

1999 Sep 23

IC23 Data Handbook



74LVT162373

FEATURES

- 16-bit transparent latch
- 3-State buffers
- Output capability: +12 mA / -12 mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5 V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Outputs include series resistance of 30 Ω making external resistors unnecessary
- Power-up reset
- Power-up 3-State
- No bus current loading when output is tied to 5 V bus
- Latch-up protection exceeds 500 mA per JEDEC Std 17
- ESD protection exceeds 2000 V per MIL STD 883 Method 3015 and 200 V per Machine Model

DESCRIPTION

The 74LVT162373 is a high-performance BiCMOS product designed for V_{CC} operation at 3.3 V.

This device is a 16-bit transparent D-type latch with non-inverting 3-State bus compatible outputs. The device can be used as two 8-bit latches or one 16-bit latch. When Latch Enable (LE) input is High, the Q outputs follow the data (D) inputs. When Latch Enable is taken Low, the Q outputs are latched at the levels of the D inputs one setup time prior to the High-to-Low transition.

The 74LVT162373 is designed with 30 Ω series resistance in both the High and Low states of the output. This design reduces the noise in applications such as memory address drivers, clock drivers, and bus receivers/transmitters.

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25 °C	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay nDx to nQx	C _L = 50 pF; V _{CC} = 3.3 V	3.0	ns
C _{IN}	Input capacitance	V _I = 0 V or 3.0 V	3	pF
C _{OUT}	Output capacitance	Outputs disabled; $V_O = 0 V \text{ or } 3.0 V$	9	pF
I _{CCZ}	Total supply current	Outputs disabled; $V_{CC} = 3.6 V$	70	μA

ORDERING INFORMATION

QUICK REFERENCE DATA

PACKAGES	TEMPERATURE RANGE	ORDERING CODE	DWG NUMBER	
48-Pin Plastic SSOP Type III	–40 °C to +85 °C	74LVT162373 DL	SOT370-1	
48-Pin Plastic TSSOP Type II	–40 °C to +85 °C	74LVT162373 DGG	SOT362-1	

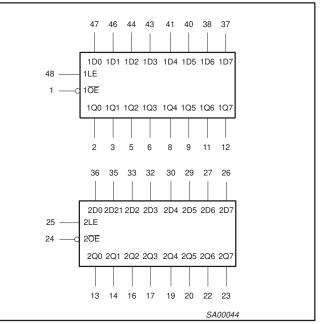
74LVT162373

PIN CONFIGURAT	ION		
		-	
10E		48	1LE
1Q0	2	47	1D0
1Q1	3	46	1D1
GND	4	45	GND
1Q2	5	44	1D2
1Q3	6	43	1D3
VCC	7	42	VCC
1Q4	8	41	1D4
1Q5	9	40	1D5
GND	10	39	GND
1Q6	11	38	1D6
1Q7	12	37	1D7
2Q0	13	36	2D0
2Q1	14	35	2D1
GND	15	34	GND
2Q2	16	33	2D2
2Q3	17	32	2D3
VCC	18	31	VCC
2Q4	19	30	2D4
2Q5	20	29	2D5
GND	21	28	GND
2Q6	22	27	2D6
2Q7	23	26	2D7
2 0E	24	25	2LE
	L	J SA(00043

PIN DESCRIPTION

i							
PIN NUMBER	SYMBOL	FUNCTION					
47, 46, 44, 43, 41, 40, 38, 37, 36, 35, 33, 32, 30, 29, 27, 26	1D0 – 1D7 2D0 – 2D7	Data inputs					
2, 3, 5, 6, 8, 9, 11, 12, 13, 14, 16, 17, 19, 20, 22, 23	1Q0 – 1Q7 2Q0 – 2Q7	Data outputs					
1, 24	1 <u>0E</u> , 2 <u>0E</u>	Output Enable inputs (active-Low)					
48, 25	1LE, 2LE	Latch Enable inputs (active-High)					
4, 10, 15, 21, 28, 34, 39, 45	GND	Ground (0V)					
7, 18, 31, 42	V _{CC}	Positive supply voltage					

LOGIC SYMBOL

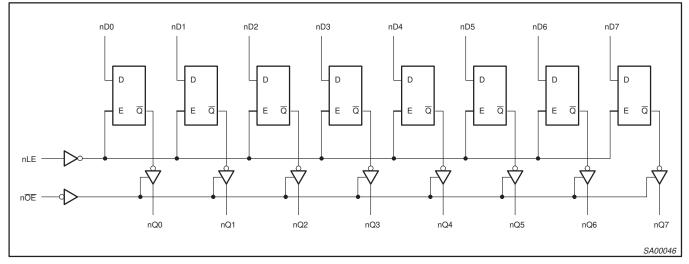


LOGIC SYMBOL (IEEE/IEC)

		_		
				1
10E	<u> </u>	1EN		
1LE	48	C3		
20E	24	2EN		
2LE	25	C4		
		<u> </u>]
1D1	47	3D	1 🗸	2 1Q1
1D2	46	-		3 1Q2
1D3	44	-		5 1Q3
1D4	43	-		<u>6</u> 1Q4
1D5	41	-		8 1Q5
1D6	40			<u> </u>
1D7	38			<u>11</u> 1Q7
1D8	37			12 1Q8
2D1	36	4D	2 \(\not\)	<u>13</u> 2Q1
2D1	35		2 1	14 2Q2
	33	1		
2D3	32	1		
2D4		1		17 2Q4
2D5	30			19 2Q5
2D6	29	- <u> </u>		<u>20</u> 2Q6
2D7	27	-		22 2Q7
2D8	26	-		232Q8
				SW00010
				0

74LVT162373

LOGIC DIAGRAM



FUNCTION TABLE

	INPUTS			OUTPUTS			
nOE	nLE	nDx	REGISTER	nQ0 – nQ7	OPERATING MODE		
L	H H	L H	L H	L H	Enable and read register		
L	\rightarrow \rightarrow	l h	L H	L H	Latch and read register		
L	L	Х	NC	NC	Hold		
H H	L H	X nDx	NC nDx	Z Z	Disable outputs		

High voltage level Н =

High voltage level one set-up time prior to the High-to-Low E transition h =

Low voltage level L =

I = Low voltage level one set-up time prior to the High-to-Low E transition

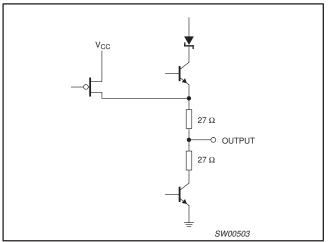
NC= No change

X = Don't care

High impedance "off" state High-to-Low LE transition Ζ =

 \downarrow =

SCHEMATIC OF EACH OUTPUT



74LVT162373

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	PARAMETER CONDITIONS		UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
1		Output in Low state	128	
IOUT	DC output current	Output in High state	-64	- mA
T _{stg}	Storage temperature range		-65 to +150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction 2. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT	
STWBOL	FANAMEIEN	MIN	МАХ	UNIT
V _{CC}	DC supply voltage	2.7	3.6	V
VI	Input voltage	0	5.5	V
V _{IH}	High-level input voltage	2.0		V
V _{IL}	Input voltage		0.8	V
I _{ОН}	High-level output current		-12	mA
I _{OL}	Low-level output current		12	mA
Δt/Δv	Input transition rise or fall rate; Outputs enabled		10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

DC ELECTRICAL CHARACTERISTICS

SYMBOL PARAMETER					LIMITS		
		TEST CONDITIONS	Temp = -40°C to +85°			C UNIT	
				MIN	TYP ¹	MAX	1
V _{IK}	Input clamp voltage	$V_{CC} = 2.7V; I_{IK} = -18mA$			-0.85	-1.2	V
V _{OH}	High-level output voltage	$V_{CC} = 3.0V; I_{OH} = -12mA$		2.0			
V _{OL}	Low-level output voltage	V _{CC} = 3.0V; I _{OL} = 16mA				0.8	V
V _{RST}	Power-up output Low voltage ⁵	V_{CC} = 3.6V; I _O = 1mA; V _I = GND or V _{CC})		0.1	0.55	V
		$V_{CC} = 3.6V; V_I = V_{CC} \text{ or } GND$	Control pins		0.1	±1	
	terrest to also an economicat	V _{CC} = 0 or 3.6V; V _I = 5.5V			0.4	10	
t _i	Input leakage current	$V_{CC} = 3.6V; V_I = V_{CC}$	Dete size4		0.1	1	μA
		$V_{CC} = 3.6V; V_I = 0$	Data pins ⁴		-0.4	-5	
I _{OFF}	Output off current	$V_{CC} = 0V; V_{I} \text{ or } V_{O} = 0 \text{ to } 4.5V$		0.1	±100	μΑ	
		$V_{CC} = 3V; V_I = 0.8V$		75	135		
I _{HOLD}	Bus Hold current D inputs ⁷	$V_{CC} = 3V; V_{I} = 2.0V$		-75	-135		μΑ
		$V_{CC} = 0V$ to 3.6V; $V_{CC} = 3.6V$		±500			
I_{EX}	Current into an output in the High state when $V_O > V_{CC}$	$V_{O} = 5.5V; V_{CC} = 3.0V$			50	125	μA
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} \leq$ 1.2V; V_O = 0.5V to $V_{CC};~V_I$ = GN OE/OE = Don't care	D or V _{CC} ;		1	±100	μA
I _{OZH}	3-State output High current	V_{CC} = 3.6V; V_{O} = 3.0V; V_{I} = V_{IH} or V_{IL}			0.5	5	
I _{OZL}	3-State output Low current	V_{CC} = 3.6V; V_{O} = 0.5V; V_{I} = V_{IH} or V_{IL}		0.5	-5	μA	
I _{CCH}		V_{CC} = 3.6V; Outputs High, V_{I} = GND or $V_{CC,\ I_{O}}$ = 0			0.07	0.12	
I _{CCL}	Quiescent supply current	$V_{CC} = 3.6V$; Outputs Low, $V_{I} = GND$ or		4.0	6	mA	
I _{CCZ}		$V_{CC} = 3.6V$; Outputs Disabled; $V_I = GNE$	0 or V_{CC} , $I_{O} = 0^{6}$		0.07	0.12	
ΔI_{CC}	Additional supply current per input pin ²	$V_{CC} = 3V$ to 3.6V; One input at V_{CC} -0.6 Other inputs at V_{CC} or GND	V,		0.1	0.2	mA

NOTES:

All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.
This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND.
This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 0.3V a transition time of 100µsec is permitted. This parameter is valid for T_{amb} = 25°C only.
Unused pins at V_{CC} or GND.
For valid test results, data must not be loaded into the flip-flops (or latches) after applying power.

6. I_{CCZ} is measured with outputs pulled to V_{CC} or GND. 7. This is the bus hold overdrive current required to force the input to the opposite logic state.

74LVT162373

AC CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5ns$; $C_L = 50pF$; $R_L = 500\Omega$; $T_{amb} = -40^{\circ}C$ to +85°C.

SYMBOL	PARAMETER	WAVEFORM	Vc	_C = 3.3V ±0	V _{CC} = 2.7V	UNIT	
			MIN	TYP ¹	MAX	MAX	
t _{PLH} t _{PHL}	Propagation delay nDx to nQx	2	0.5 0.5	2.5 2.5	4.6 4.0	5.1 4.3	ns
t _{PLH} t _{PHL}	Propagation delay nLE to nQx	1	0.5 0.5	3.0 3.0	5.1 4.6	5.8 4.3	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	4 5	0.1 0.1	3.5 3.2	5.4 4.9	6.6 5.5	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low Level	4 5	0.1 0.1	3.5 3.2	5.4 5.1	5.7 5.0	ns

NOTE:

1. All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^{\circ}C$.

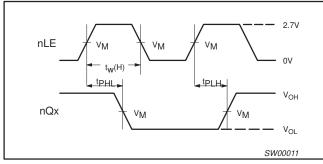
AC SETUP REQUIREMENTS

GND = 0V; $t_R = t_F = 2.5ns$; $C_L = 50pF$; $R_L = 500\Omega$; $T_{amb} = -40^{\circ}C$ to +85°C.

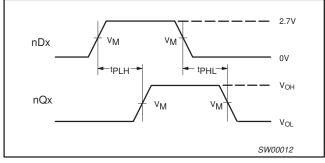
	PARAMETER					
SYMBOL		WAVEFORM	V _{CC} = 3.3V ±0.3V		$V_{CC} = 2.7V$	UNIT
			MIN	ТҮР	MIN	
t _S (H) t _S (L)	Setup time nDx to nLE	3	1.5 2.0	0.1 0.2	1.0 2.0	ns
t _h (H) t _h (L)	Hold time nDx to nLE	3	1.0 1.5	0 0	1.0 2.0	ns
t _W (H)	nLE pulse width High	1	1.5	0.5	1.5	ns

AC WAVEFORMS

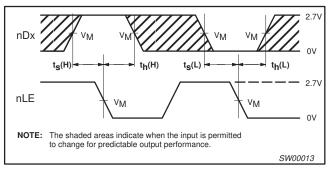
For all waveforms, $V_M = 1.5V$.



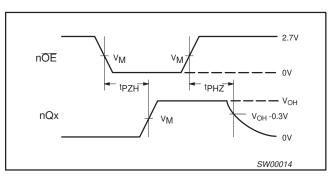
Waveform 1. Propagation Delay, Latch Enable to Output, and Latch Enable Pulse Width



Waveform 2. Propagation Delay for Data to Outputs



Waveform 3. Data Setup and Hold Times

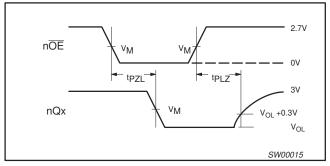


Waveform 4. 3-State Output Enable time to High Level and Output Disable Time from High Level

SW00003

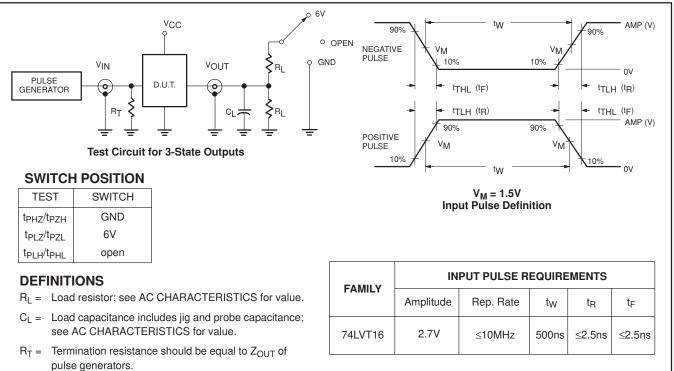
3.3 V LVT 16-bit transparent D-type latch with 30 Ω termination resistors (3-State)





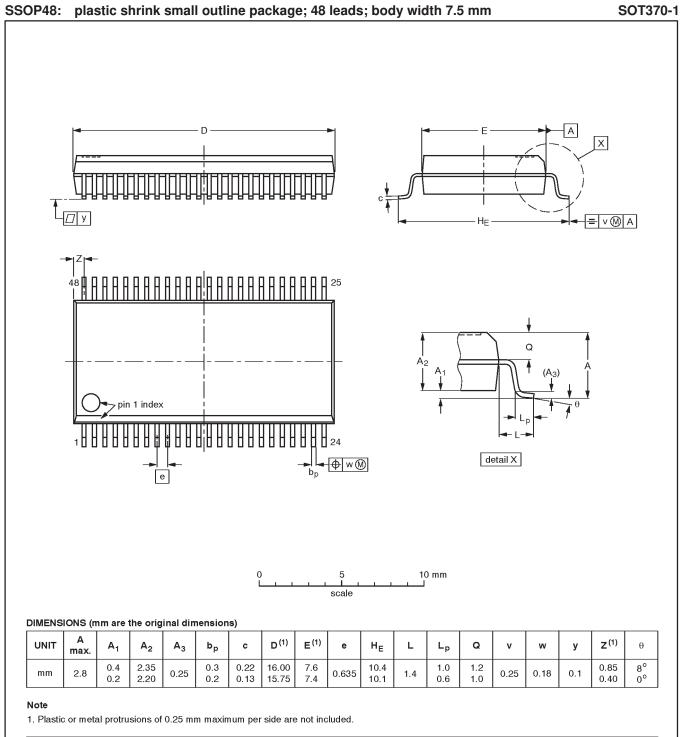
Waveform 5. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

TEST CIRCUIT AND WAVEFORMS



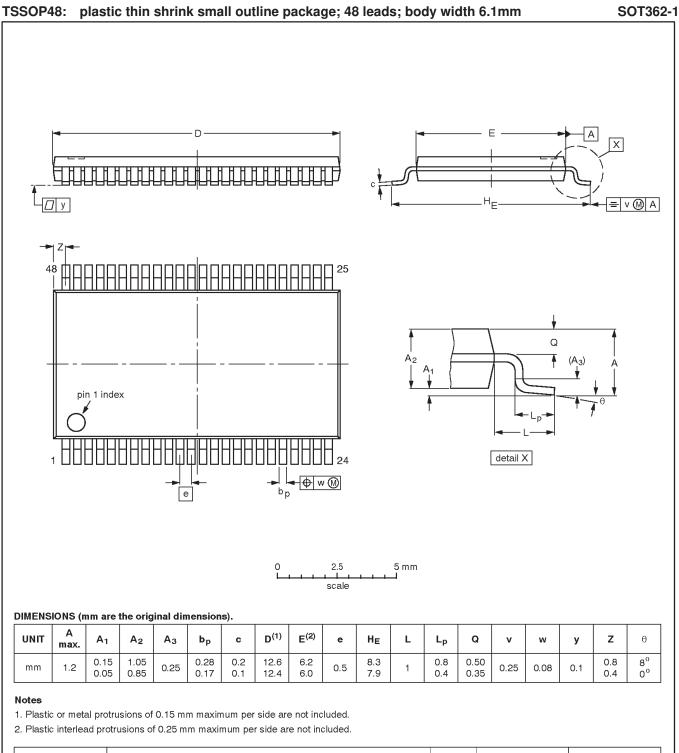
1999 Sep 23

74LVT162373



OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE	
VERSION	IEC	IEC JEDEC EIA			PROJECTION	ISSUE DATE	
SOT370-1		MO-118AA				-93-11-02 95-02-04	

74LVT162373



OUTLINE VERSION	REFERENCES				EUROPEAN	ISSUE DATE
	IEC	JEDEC	EIAJ		PROJECTION	1550E DATE
SOT362-1		MO-153ED				- 93-02-03 95-02-10

74LVT162373

NOTES

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